



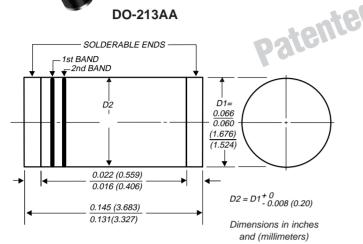
Vishay Semiconductors formerly General Semiconductor



Surface Mount Glass Passivated Junction Fast Switching Rectifiers

Reverse Voltage 50 to 800V Forward Current 0.5A

DO-213AA



1st band denotes type and polarity 2nd band denotes voltage type

*Glass-plastic encapsulation is covered by Patent No. 3,996,602 and brazed-lead assembly to Patent No. 3,930,306



Features

- Plastic package has Underwriters Laboratories Flammability Classification 94V-0
- For surface mount applications
- High temperature metallurgically bonded construction
- · Cavity-free glass passivated junction
- Capable of meeting environmental standards of MIL-S-19500
- Fast switching for high efficiency
- High temperature soldering guaranteed: 450°C/5 seconds at terminals. Complete device submersible temperature of 260°C for 10 seconds in solder bath

Mechanical Data

Case: JEDEC DO-213AA, molded plastic over glass body Terminals: Plated terminals, solderable per MIL-STD-750, Method 2026

Polarity: Two bands indicate cathode end - 1st band denotes device type and 2nd band denotes repetitive peak reverse voltage rating

Mounting Position: Any Weight: 0.0014 oz., 0.036 g

Packaging codes/options: 33/9K per 13" Reel (8mm tape) 48/2.5K per 7" Reel (8mm tape)

Maximum Ratings & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Fast switching device: 1st band is Red	Symbol	RGL34A	RGL34B	RGL34D	RGL34G	RGL34J	RGL34K	Unit
Polarity color bands (2nd Band)		Gray	Red	Orange	Yellow	Green	Blue	
Maximum repetitive peak reverse voltage	VRRM	50	100	200	400	600	800	V
Maximum RMS voltage	VRMS	35	70	140	280	420	560	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	V
Max. average forward rectified current at T _T = 55°C	IF(AV)	0.5						Α
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	10						Α
Max. full load reverse current, full cycle average T _A = 55°C	IR(AV)	30						μΑ
Maximum thermal resistance ⁽¹⁾ (2)	RθJA RθJT	150 70						°C/W
Operating junction and storage temperature range	TJ, TSTG	−65 to +175						°C

Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

	Symbol	RGL34A	RGL34B	RGL34D	RGL34G	RGL34J	RGL34K	Unit
Maximum instantaneous forward voltage at 0.5A	VF	1.3					V	
Maximum DC reverse current $T_A = 25^{\circ}C$ at rated DC blocking voltage $T_A = 125^{\circ}C$	IR	5.0 50					μΑ	
Maximum reverse recovery time at IF = 0.5A, IR = 1.0A, Irr = 0.25A	t _{rr}			1	50	2	50	ns
Typical junction capacitance at 4.0V, 1MHz	CJ			4	.0			pF

Notes: (1) Thermal resistance from junction to ambient, 0.2 x 0.2" (5.0 x 5.0mm) copper pads to each terminal

(2) Thermal resistance from junction to terminal, 0.2 x 0.2" (5.0 x 5.0mm) copper pads to each terminal

RGL34A thru RGL34K

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Ratings and

Characteristic Curves (TA = 25°C unless otherwise noted)

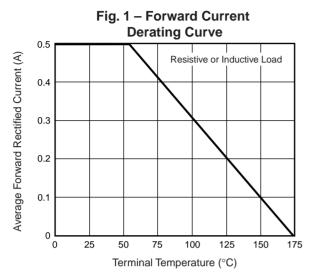
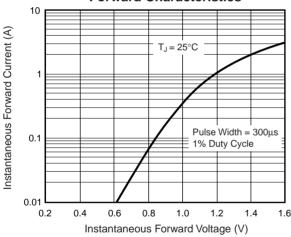


Fig. 3 - Typical Instantaneous **Forward Characteristics**



10 T_J = 25°C f = 1.0 MH_Z Vsig = 50mVp-p Junction Capacitance (pF)

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Reverse Voltage (V)

Fig. 5 - Typical Junction Capacitance

Fig. 2 – Maximum Non-Repetitive Peak **Forward Surge Current**

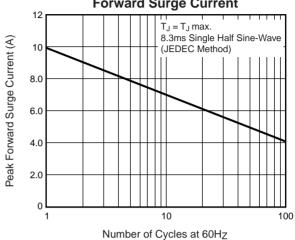
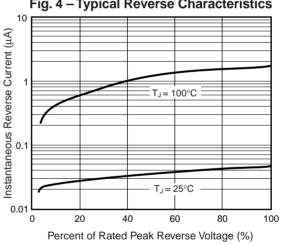


Fig. 4 - Typical Reverse Characteristics



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100